Corrigendum: Topological crystalline insulators in the SnTe material class

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In the Discussion section of this Article, we incorrectly claimed that an in-plane magnetic field will generate Dirac mass terms for the surface states. Instead, the in-plane magnetic field merely shifts the location of the Dirac points. The $k \cdot p$ Hamiltonian in the presence of an in-plane field (B_1, B_2) (in the local basis defined in the Article) is

$$H_{sf,B} = v_\perp k_1 s_2 - v_\parallel k_2 s_1 + g_1 \mu_B B_1 s_1 + g_2 \mu_B B_2 s_2 \tag{10}$$

$$= v_\perp (k_1 + \frac{g_2 \mu_B B_2}{v_\perp}) s_2 - v_\parallel (k_2 - g_1 \mu_B \frac{B_1}{v_\parallel}) s_1 \tag{11}$$

where μ_B is the Bohr magneton and $g_{1,2}$ is the g-factor of Dirac surface states.